

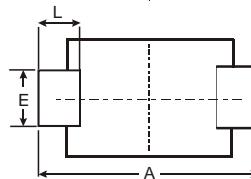
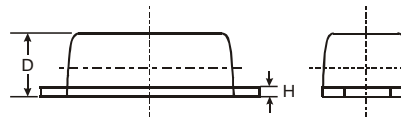
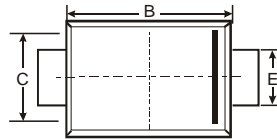
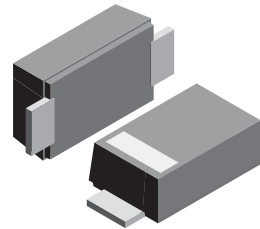
**VOLTAGE RANGE: 50V-1000 V**  
**CURRENT: 3.0 A**

### Features

- Glass Passivated Die Construction
- Fast Recovery Time for High Efficiency
- Low Forward Voltage Drop and High Current Capability
- Ideally Suited for Automatic Assembly
- Plastic Material: UL Flammability Classification Rating 94V-0

### Mechanical Data

- Case:SMBF , Molded Plastic
- Terminals: Solder Plated, Solderable per MIL-STD-750, Method 2026
- Polarity: Cathode Band or Cathode Notch
- Marking: Type Number
- Weight: 0.0018 ounces,0.05grams



SMBF			
Dim	Min	Max	Typ
A	5.45	5.55	5.50
B	4.27	4.33	4.30
C	3.57	3.63	3.60
D	1.32	1.38	1.35
E	1.96	2.00	1.98
H	0.019	0.021	0.20
L	0.73	0.77	0.75
All Dimensions in mm			

### Maximum Ratings and Electrical Characteristics $T_A = 25^\circ\text{C}$ unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	RS3AAF	RS3BAF	RS3DAF	RS3GAF	RS3JAF	RS3KAF	RS3MAF	Unit
Maximum repetitive peak reverse voltage	$V_{RRM}$	50	100	200	400	600	800	1000	V
Maximum RMS voltage	$V_{RMS}$	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	$V_{DC}$	50	100	200	400	600	800	1000	V
Maximum average forward rectified current at $T_L=75^\circ\text{C}$	$I_{(AV)}$	3.0							A
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	$I_{FSM}$	100.0							A
Maximum instantaneous forward voltage at 3.0A	$V_F$	1.3							V
Maximum DC reverse current $T_A=25^\circ\text{C}$ at rated DC blocking voltage $T_A=100^\circ\text{C}$	$I_R$	5.0 100.0							$\mu\text{A}$
Maximum reverse recovery time (NOTE 1)	$t_{rr}$	150				250	500		ns
Typical junction capacitance (NOTE 2)	$C_J$	60.0							pF
Typical thermal resistance (NOTE 3)	$R_{\theta JA}$	50.0							$^\circ\text{C/W}$
Operating junction and storage temperature range	$T_J, T_{STG}$	-50 to +150							$^\circ\text{C}$

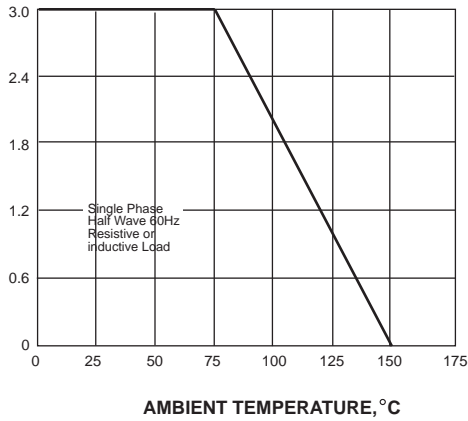
**Note:** 1.Reverse recovery condition  $I_F=0.5\text{A}, I_R=1.0\text{A}, I_{rr}=0.25\text{A}$   
 2.Measured at 1MHz and applied reverse voltage of 4.0V D.C.  
 3.P.C.B. mounted with 0.2x0.2" (5.0x5.0mm) copper pad areas



## RATINGS AND CHARACTERISTIC CURVES RS3AAF THRU RS3MAF

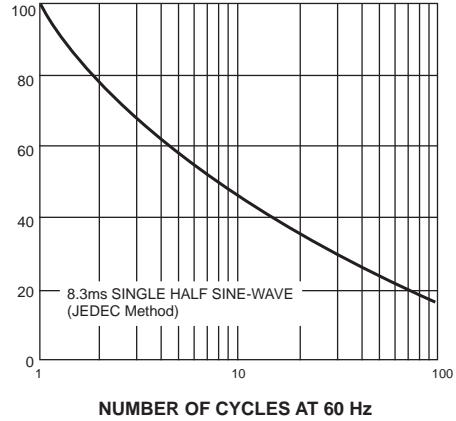
AVERAGE FORWARD RECTIFIED CURRENT, AMPERES

FIG. 1- FORWARD CURRENT DERATING CURVE



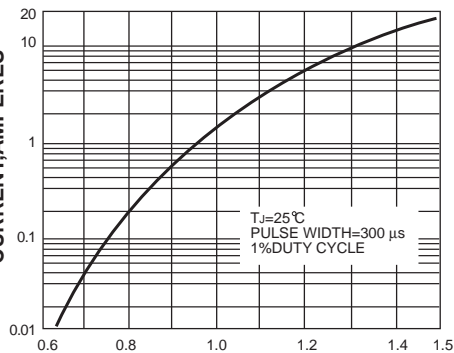
PEAK FORWARD SURGE CURRENT, AMPERES

FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT



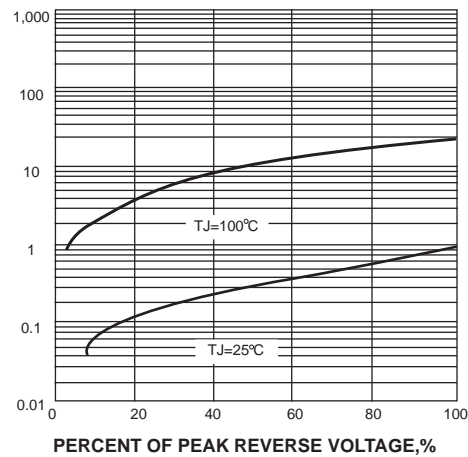
INSTANTANEOUS FORWARD CURRENT, AMPERES

FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS



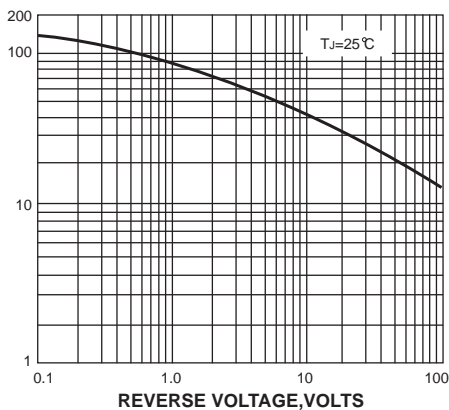
INSTANTANEOUS REVERSE CURRENT, MICROAMPERES

FIG. 4-TYPICAL REVERSE CHARACTERISTICS



JUNCTION CAPACITANCE, pF

FIG. 5-TYPICAL JUNCTION CAPACITANCE



TRANSIENT THERMAL IMPEDANCE, °C/W

FIG. 6-TYPICAL TRANSIENT THERMAL IMPEDANCE

